

MJD44E3

Preferred Device

Darlington Power Transistor

DPAK For Surface Mount Applications

Designed for general purpose power and switching output or driver stages in applications such as switching regulators, converters, and power amplifiers.

Features

- Electrically Similar to Popular D44E3 Device
- High DC Gain – 1000 Min @ 5.0 Adc
- Low Sat. Voltage – 1.5 V @ 5.0 Adc
- Compatible With Existing Automatic Pick and Place Equipment
- Epoxy Meets UL 94, V-0 @ 0.125 in.
- ESD Ratings: Human Body Model, 3B > 8000 V
Machine Model, C > 400 V

MAXIMUM RATINGS

Rating	Symbol	Max	Unit
Collector–Emitter Voltage	V_{CEO}	80	Vdc
Emitter–Base Voltage	V_{EB}	7	Vdc
Collector Current – Continuous	I_C	10	Adc
Total Power Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	20 0.16	W W/ $^\circ\text{C}$
Total Power Dissipation* @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	1.75 0.014	W W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	–55 to +150	$^\circ\text{C}$

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction–to–Case	$R_{\theta JC}$	6.25	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction–to–Ambient*	$R_{\theta JA}$	71.4	$^\circ\text{C}/\text{W}$
Lead Temperature for Soldering	T_L	260	$^\circ\text{C}$

*These ratings are applicable when surface mounted on the minimum pad sizes recommended.

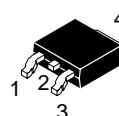


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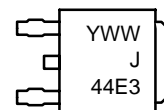
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**NPN DARLINGTON SILICON
POWER TRANSISTORS
10 AMPERES
80 VOLTS
20 WATTS**

MARKING DIAGRAM



DPAK
CASE 369C
STYLE 1



Y = Year
WW = Work Week

ORDERING INFORMATION

Device	Package	Shipping†
MJD44E3T4	DPAK	2500/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Preferred devices are recommended choices for future use and best overall value.

MJD44E3

ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
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OFF CHARACTERISTICS

Collector Cutoff Current ($V_{CE} = \text{Rated } V_{CE0}, V_{BE} = 0$)	I_{CES}	-	-	10	μA
Emitter Cutoff Current ($V_{EB} = 7 \text{ Vdc}$)	I_{EBO}	-	-	1	μA

ON CHARACTERISTICS

Collector-Emitter Saturation Voltage ($I_C = 5 \text{ Adc}, I_B = 10 \text{ mAdc}$) ($I_C = 10 \text{ Adc}, I_B = 20 \text{ mAdc}$)	$V_{CE(\text{sat})}$	-	-	1.5 2	Vdc
Base-Emitter Saturation Voltage ($I_C = 5 \text{ Adc}, I_B = 10 \text{ mAdc}$)	$V_{BE(\text{sat})}$	-	-	2.5	Vdc
DC Current Gain ($V_{CE} = 5 \text{ Vdc}, I_C = 5 \text{ Adc}$)	h_{FE}	1000	-	-	-

DYNAMIC CHARACTERISTICS

Collector Capacitance ($V_{CB} = 10 \text{ Vdc}, f_{\text{test}} = 1 \text{ MHz}$)	C_{cb}	-	-	130	pF
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SWITCHING TIMES

Delay and Rise Times ($I_C = 10 \text{ Adc}, I_{B1} = 20 \text{ mAdc}$)	$t_d + t_r$	-	0.6	-	μs
Storage Time ($I_C = 10 \text{ Adc}, I_{B1} = I_{B2} = 20 \text{ mAdc}$)	t_s	-	2	-	μs
Fall Time ($I_C = 10 \text{ Adc}, I_{B1} = I_{B2} = 20 \text{ mAdc}$)	t_f	-	0.5	-	μs

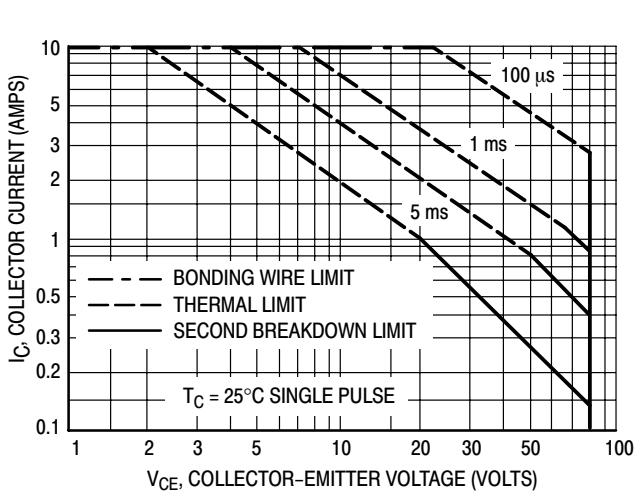


Figure 1. Maximum Forward Bias Safe Operating Area

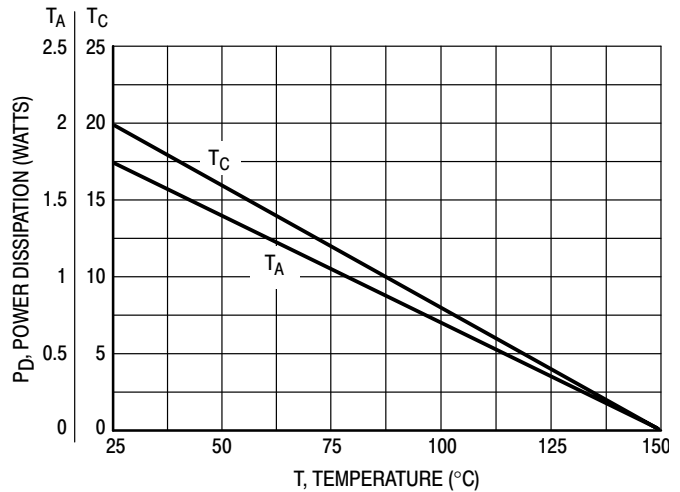
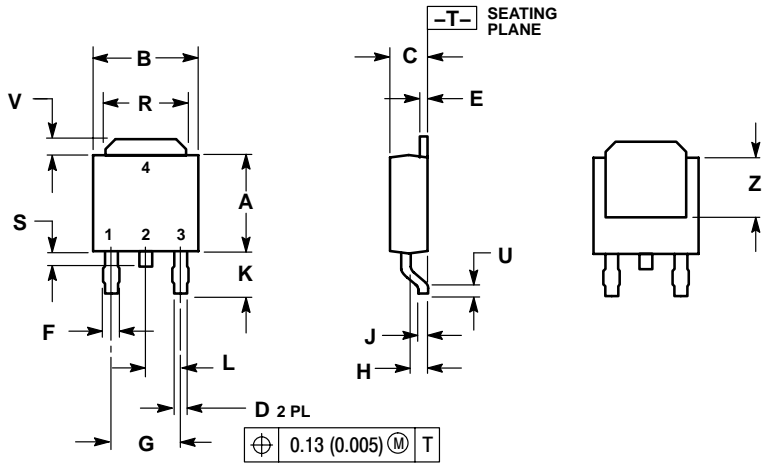


Figure 2. Power Derating

MJD44E3

PACKAGE DIMENSIONS

DPAK
CASE 369C-01
ISSUE O

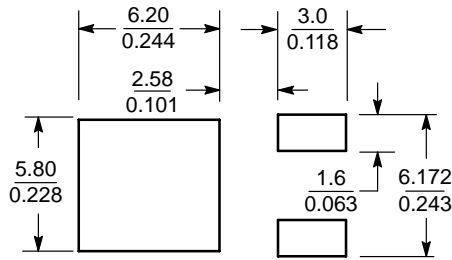


- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.


DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.235	0.245	5.97	6.22
B	0.250	0.265	6.35	6.73
C	0.086	0.094	2.19	2.38
D	0.027	0.035	0.69	0.88
E	0.018	0.023	0.46	0.58
F	0.037	0.045	0.94	1.14
G	0.180 BSC		4.58 BSC	
H	0.034	0.040	0.87	1.01
J	0.018	0.023	0.46	0.58
K	0.102	0.114	2.60	2.89
L	0.090 BSC		2.29 BSC	
R	0.180	0.215	4.57	5.45
S	0.025	0.040	0.63	1.01
U	0.020	---	0.51	---
V	0.035	0.050	0.89	1.27
Z	0.155	---	3.93	---

- STYLE 1:
PIN 1. BASE
2. COLLECTOR
3. EMITTER
4. COLLECTOR

SOLDERING FOOTPRINT



SCALE 3:1 $\left(\frac{\text{mm}}{\text{inches}}\right)$

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